## ABSTRACT OF THE DISCLOSURE

Inperder to provide a magnetic loss material exhibiting outstanding high frequency magnetic loss characteristics extremely effective in eliminating highfrequency transmission noise from very densely integrated electropic microcircuits such as semiconductor integrated circumference devices, together with a manufacturing method therefor and a high-frequency current suppression body wherein such is used, the present invention is a high-frequency current suppression body having a sheet shape comprising an adhesive layer or a pressure-sensitive adhesive layer (23) on at least one surface of a magnetic thin film (19). This magnetic thin film is a magnetic loss material consisting of M-X-Y, where M is at least one of Fe, Co, and Ni, X is at least one element other than M or Y, and Y is at least one of F, N, and O. The maximum value μ"max of the loss factor μ" of the magnetic loss material exists in a frequency range of 100/MHz to 10 GHz. A relative bandwidth bwr is not greater than 200% where the relative bandwidth bwr is obtained by extracting a frequency bandwidth between two frequencies at which the value of µ" is 50% of the maximum  $\mu''_{max}$  and normalizing the frequency bandwidth at the center frequency thereof.

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